9,4300 (1143, 1151, 1136)

S/181/61/003/005/031/042 B108/B209

Landsberg, Ye. G. and Kalashnikov, S.G.

TITLE:

Electron capture cross section of manganese atoms in

germanium

PERIODICAL: Fizika tverdogo tela, v. 3, no. 5, 1961, 1566 - 1570

TEXT: The authors studied the temperature dependence of the electron lifetime in p-type germanium containing high-purity manganese. The manganese concentration was determined from the variation in the temperature dependence of the Hall constant. For this purpose, an ingot with a given antimony concentration was prepared, whose electron concentration n (equaling the difference between donor and acceptor concentrations Nd - Na) was measured. After this, manganese was added so that the lower manganese level was partly filled with electrons. Fig. 1 shows the result. The obtained concentration of manganese atoms, Nt, corresponds to a distribution coefficient, k, of about 1.5.10-6. Gallium was introduced Card 1/5

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Electron capture cross...

S/181/61/003/005/031/042 B108/B209

into the crystals in order to obtain samples with a known hole concentration. The Hall constant was measured in a field of 3600 oersteds. After this the crystals were melted, and manganese was added. The properties of the samples are given in the Table. The lifetime was measured by a method of compensating the voltage of the photomagnetic effect and the photoconductivity (Ref. 4: S. G. Kalashnikov, Ye. G. Landsberg. ZhTF, XXVIII, 1387, 1958). Measurements were made in the temperature interval of from 95 to 330°K and showed a decrease in electron lifetime with rising manganese content. The manganese atoms in p-type germanium were found not to give rise to a noticeable adhesion. Considering that, according to Ref. 1 (H. H. Woodbury a. W. W. Tyler. Phys. Rev., 100, 659, 1955), manganese produces two levels in germanium (E<sub>1</sub> - E<sub>2</sub> = 0.16 ev and E<sub>2</sub> - E<sub>2</sub> = 0.37 ev), the theoretical expression for the lifetime under the present

conditions reads:  $\tau = \frac{p_o + p_1}{c_{n1}p_o + c_{n2}p_1}$  (1), where  $c_{n1} = NvS_{n1}$ ;  $c_{n2} = NvS_{n2}$ ;  $c_{n2} = nvS_{n2}$ ;  $c_{n1}$  and  $c_{n2}$  are the electron capture cross sections for the lower and the Card 2/5

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Electron capture cross...

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upper level, respectively; v is the velocity of thermal motion of electrons;  $p_1 = \frac{g_1}{g_0} N_v \exp \frac{E_v - E_1}{kT}$  (2);  $g_1$  and  $g_0$  are the degeneration multiplicity factors of the completed and of the empty level  $E_1$ ;  $N_v$  denotes the effective phase density in the valence band. The capture cross sections calculated from experimental data on lifetime and manganese concentration were found to be  $S_{n1} = 2 \cdot 10^{-16}$  cm<sup>2</sup> (90°K) and  $S_{n2} = 4 \cdot 10^{-17}$  cm<sup>2</sup> (300°K). The mean velocity of thermal motion of electrons at 300°K was taken to be 1.07·10<sup>7</sup> cm/sec. The results showed only a slight temperature dependence of the capture cross sections, which is typical of deep acceptor levels in germanium. The lower level is ascribed to Mn ions, and the upper one to Mn ions. The high capture cross section  $S_{n1}$  is explained by a theory established by M. Lax (Ref. 10: J. Phys. Chem. Sol., 8, 66, 1959) who considered capture to be a sequence of single-phonon processes in which excited centers take part. The  $S_{n2}$  capture (electron capture on Mn ions) is ascribed to the tunnel effect in the presence of a Coulomb barrier.

\$/181/61/003/005/031/042 Electron capture cross... B108/B209 There are 3 figures, 1 table and 20 references: 8 Soviet-bloc and 11 non-Soviet-bloc. ASSOCIATION: Institut radiotekhniki i elektroniki AN SSSR Moskva (Institute of Radio Engineering and Electronics AS USSR, Moscow) . SUBMITTED: November 30, 1960 Table. Пантиость мизии т<sub>р</sub> мисек. Legend: 1) Number of sample; 2)hole concentration po, cm<sup>-3</sup>; 1.0 · 10<sup>15</sup>
1.4 · 10<sup>15</sup>
2.8 · 10<sup>13</sup>
2.1 · 10<sup>13</sup>
4.8 · 10<sup>15</sup>
6.0 · 10<sup>15</sup> 5.0 · 10<sup>13</sup> · 1.0 · 10<sup>14</sup> 2.0 · 10<sup>14</sup> 2.6 · 10<sup>14</sup> 6.0 · 10<sup>14</sup> 1.1 · 10<sup>15</sup> 50 26 15 12 3) manganese concentration 900 800 100 500 1200  $N_{\perp}$ , cm<sup>-3</sup>; 4)lifetime  $\tau_{n02}$ , dec;

5)lifetime (nO1, usec; 6)density

of dislocations Nd, cm

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36471 \$/181/62/004/003/010/045 B102/B104

AUTHORS:

Karpova, I. V., Alekseyeva, V. G., and Kalashnikov, S. G.

TITLE:

Recombination properties of gold in n-type germanium

PERIODICAL: Fizika tverdogo tela, v. 4, no. 3, 1962, 634 - 641

TEXT: This paper is to complete previous studies (FTT, 3, 964, 1961) about p-type Ge. The data available up to now, especially those on Au electron-trapping cross sections, diverge considerably and the temperature dependence of these cross sections is not sufficiently investigated. n-type Ge single crystals were grown from 99.9% Ge and from Ge of even higher purity. Both series of samples were doped with Au and Sb of such concentrations that the temperature dependences of the electron concentrations, logn = f(1/T), showed separate and distinct plateaus. The overall lifetime was measured between 100 and 330°K photoelectromagnetically between 100 and 330°K (Tpem = 10-9-10-10 sec) without being affected by adhesion. It was also determined from photoconductivity (Tpa) in order to determine the effect of adhesion. Tpem and T were calculated without Card 1/3

Recombination properties ...

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consideration of surface recombination effects on the assumption that the Hall mobility is equal to the drift mobility. Electron mobility was determined from measurements of resistivity and Hall-constant. The curves of resistivity and Hall-constant. The curves log T = f(1/T) for The and The coincide at room and higher temperatures, but diverge at low temperatures. At 100°K the exceeds The for Au-doped Ge by several thousand times which is indicative of the intense adhesion of minority carriers. Adhesion increases with the Au concentration; Them is proportional to 1/C au at low temperatures. Au furnishes the major part of recombination and adhesion centers, Sb and other impurities play a minor role. This effect of Au is attributed to its level E = 0.20 ev. The hole trapping coefficient, The first part of the temperature dependence of The Attributed from the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the temperature dependence of The Attributed for the lower part of the temperature dependence of The Attributed for the temperature of the temperature

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30790 \$/181/61/003/011/033/056 B125/B138

AUTHORS:

Morozov, A. I., and Kalashnikev, S. G.

TITLE:

Adhesion phenomena in zinc-containing germanium

PERIODICAL:

Fizika tverdogo tela, v. 3, no. 11, 1961, 3473-3479

TEXT: The authors investigate photomagnetic effect and photoconductivity in n-type germanium by comparing the lives of carriers as determined from photocolectromagnetic effect ( $\tau_{\text{PEM}}$ ), from photoconductivity ( $\tau_{\text{PC}}$ ) and from photocolectromagnetic effect

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the compensation of photoelectromagnetic and photoconductivity effects

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under stationary conditions. The same apparatus is used as that described

under stationary conditions. The same apparatus is used as that described

in a previous paper (S. G. Kalashnikov, A. I. Morozov, FTT, 2, 1813, 1960).

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30790 S/181/61/003/011/033/056 Adhesion phenomena in zinc-containing... B125/B138

are applied to phenomena with linear recombination. In Fig. 1 the typical temperature dependence of  $\tau_{PEM}$ ,  $\tau_{PC}$  and  $\tau_{C}$  is shown for two samples. These three periods are equal at room temperature, but at lower temperatures they are different because of adhesion. The curves for these temperatures have the same character as the curves for copper. Unlike copper, in the case of zinc to is not inversely proportional to the concentration of zinc. Recombination must therefore pass through other centers of whose origin cannot be verified. Fig. 2 shows typical curves for the temperature dependence of the adhesion coefficient. The same values of k are found from the two relations  $\tau_{PC} = k\tau_p$  and  $\tau_e = k^2\tau_p$  (3), where  $\tau_p$  denotes the life-time of the minority carriers. k is equal to one at room temperature, but it increases at lower temperatures and reaches values of 102-102 at liquid-nitrogen temperatures. The temperature region where  $k \sim 1$  becomes narrower with increasing zinc concentration, and the absolute values of k increase. Fig. 3 shows the influence of light intensity on  $\tau_{\text{PC}}$  and on the diffusion length  $L_0$  (photoelectromagnetic effect) for one of the Card 2/6 3

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S/181/62/004/006/019/051 B104/B112

AUTHORS:

Kurova, I. A., Kalashnikov, S. G., and Tyapkina, N. D.

TITLE:

The kinetics of impurity conduction in Au-doped n-type

germanium

PERIODICAL: Fizika tverdogo tela, v. 4, no. 6, 1962, 1503 - 1509

TEXT: The trapping of electrons on the  $E_4$  level of gold in Au-doped n-type germanium was investigated at hydrogen temperature. The photoconduction of single-crystal specimens was determined in a He cryostat evacuated to  $\sim 10^{-2}$  mm Hg. The heat emission of a crucible furnace was filtered through Ge and Sb-In filters. The damping periods of the photoconduction of the specimens were measured for two different directions of current passage. If the contacts of the samples are of high quality, the damping of photoconduction can be described by  $\exp(-t/\sqrt{t})$ . The coefficients  $\sim 10^{-1}$  of electron trapping on the  $E_4$  level of gold were determined from measured values of  $\sim 10^{-1}$ , using the relation  $\sim 10^{-1}$  Card  $\sim 10^{-1}$ 

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S/181/63/005/001/045/064 B108/B180

AUTHORS:

Karpova, I. V., and Kalashnikov, S. G.

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TITLE:

Electron and hole lifetimes in highly doped germanium

PERIODICAL:

Fizika tverdogo tela, v. 5, no. 1, 1963, 301-307

TEXT: Continuing earlier work (FTT, 1, 529, 1959) the authors studied the lifetime of the excess carriers in n- and p-type Ge doped with P, Sb, and B, in dependence on the equilibrium concentration of the majority carriers. The doped samples were refined by recrystallization. To find out whether surface recombination and adhesion had any effect, the lifetime was determined by the photoelectromagnetic and photoconductive effects, and from their compensation. Below a majority carrier concentration of 10 cm<sup>-3</sup> it was also determined from measurements of diffusion length with a linear light probe and a point collector. The results obtained by these four methods agreed with one another within the limits of accuracy. They are slightly temperature dependent. In crystals of both types, after reaching a constant level of 50-60 µsec, from ~1.1017 cm<sup>-3</sup> the lifetime

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falls rapidly with rising concentration, to  $\sim 1~\mu \rm sec$  at  $\sim 10^{18}~cm^{-3}$ . This rapid decrease can be explained qualitatively by the theory of impact recombination on traps, which would also account for the slight temperature dependence. More exact experimental data would be required to prove this quantitatively. Radiative recombination in the fundamental crystal lattice is another possible process, which might fit in with the observed slight temperature dependence. There are 5 figures and 1 table.

ASSOCIATION:

Institut radiotekhniki i elektroniki AN SSSR, Moskva

(Institute of Radio Engineering and Electronics AS USSR,

Moscow)

SUBMITTED:

August 13, 1962

Card 2/2

S/181/63/005/001/048/064 B108/B180

247500

AUTHORS:

Yeliseyev, P. G., and Kalashnikov, S. G.

TITLE:

The recombinative properties of nickel in germanium

PERIODICAL: Fizika tverdogo tela, v. 5, no. 1, 1963, 320-326

TEXT: To clear up discrepancies in published data on the electron trapping cross sections of Ni and Ni in p-type Ge, the authors studied the lifetime of the excess carriers in dependence on temperature, nickel concentra: tion, and dislocation density. It was measured by two methods: (1) compensation of the photomagnetic effect by photoconductivity, (2) attenuation of photoconductivity. The results were the same in the range

120 - 330°K. The Ge crystals were doped with nickel by diffusion, either from an electrolytic layer onto the sample's surface or from a solution of nickel in molten lead. The results were qualitatively the same and slowed only a slight quantitative difference (20 - 30%). At low Ni. concentrations, the lifetime-versus-temperature curve has two plateaus, with the lifetime falling with decreasing temperature in between. As the Ni concentration increases, the curve maintains its two plateaus, but the Card 1/2

KUROVA, I.A.; KALASHNIKOV, S.G.

Electric instability in germanium. Fiz. tver. tela 5 no.11:32243230 N '63.

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4	5/181/63/005/c04/014/c47 B102/B186	
	AUTHORS: Landaberg, Ye. G., and Kalashnikov, S. C.	
	TITLE: Recombination properties manganese in germanium	
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12.	PERIODICAL: Fizika tverdogo tela, v. 5, no. 4, 1963, 067 - 1076	
	TEXT: The electron - hole recombination on manganese atoms in n-type ger-	
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	Czochralski method (growth axis [111]) and contained antimony with dangenese	
	impurities, the latter in concentrations between 8.0 012 and 1.0.1015 cm-3.  The electron concentrations of the samples under investigation were varied	
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ij.	between 2.0.1015 and 2.5.1014 and the dislocation densities between 2.102	
Ť,	and 1.7.103 cm-2. The hole trapping factor a for trapping by Mn2- ions	
	was determined at 3000k; it lies between 7.9 and 4.7. 0-10 and a -1 and	
	depends exponentially on the temperature (the arrangula very harrage to	
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V.D., red.

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Nauka, 1964. 666 p.

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ACCESSION NR: APLO13502

S/01.81/6h/006/002/0hho/ohhh

AUTHORS: Zhdanova, N. G.; Kalashnikov, S. G.

TITLE: The effect of temperature on the kinetics of damping impurity photoconductivity in copper doped germanium

SOURCE: Fizika tverdogo tela, v. 6, no. 2, 1964, 440-444

TOPIC TAGS: impurity, impurity photoconductivity, photoconductivity, germanium, copper, copper doped germanium, photoionization, photoionization cross section, capture coefficient, n type germanium

ABSTRACT: This study was made in the temperature interval 60-235K in n-type Ge by electron excitation of the outer copper level with  $E_{\rm c}=0.26$  ev. It was found that the temperature coefficient of capture for electrons from this level, throughout the rather wide investigated temperature range, differs appreciably from an exponential relationship, and is best defined by the formula

 $\epsilon_0 \sim \exp\left(-\frac{T_0}{T}\right)^{1/\epsilon}$ 

in which full consideration is given to tunnel leakage of electrons through the

Card 1/2

# potential barrier of the center. In a number of samples the damping of impurity photoconductivity was defined by two exponents with markedly different time constants. It was found that the time constant of the long exponent was not inversely proportional to no, but that the short exponent was. The time constant increased with decrease in intensity of illumination. The authors conclude that the long exponent is not associated with electron capture at the outer Cu level, and, because of this, results of experiments in which this long exponent was observed should not be used. The long exponent was observed in crystals with high dislocation density and with no dislocations. The explanation is not known. For the specimens used it was found that the photoionization cross section of the investigated level is practically independent of temperature. Orig. art. has: If figures, I table, and 2 formulas. ASSOCIATION: Institut radiotekhniki i elektroniki AN SSSR, Moscow (Institute of Radio Engineering and Electronics AN SSSR)

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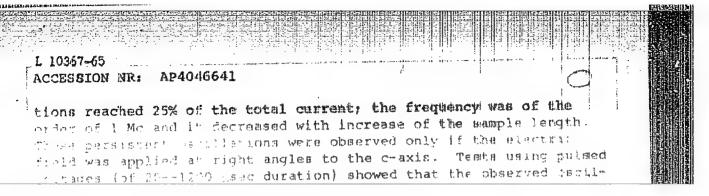
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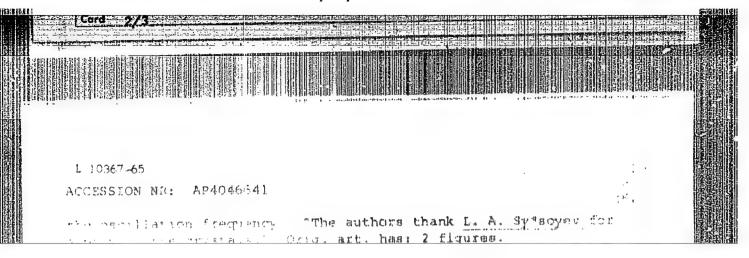
TOPIC PAGS: Tadmium suifide photoconductivity. Hall effect car-

ABSTRACT: The authors investigated n-type crystals, 0.3-0.8 cm long, with a dark conductivity <10 ohm lcm land a Hall mobility 1250 cm l.V lsec l. The electric field was directed either parallel of tright angles to the hexagonal c-axis. Pecsistent current os a contract con

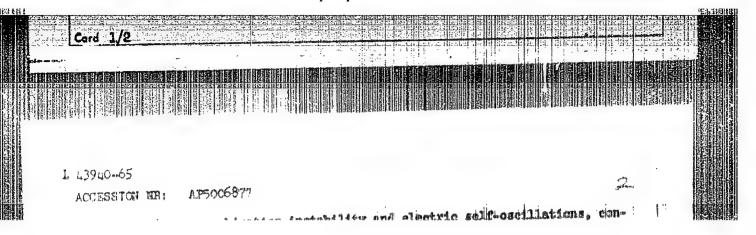
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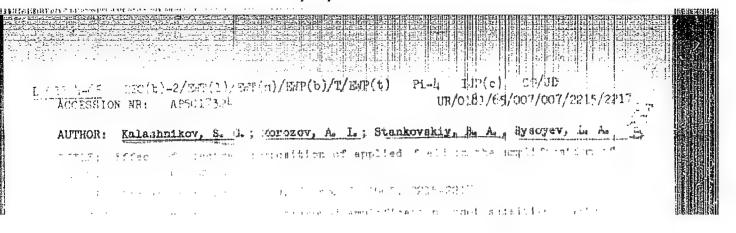


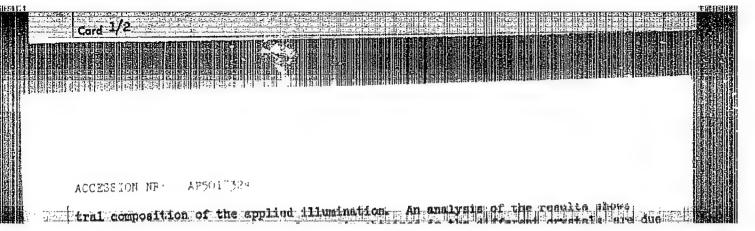


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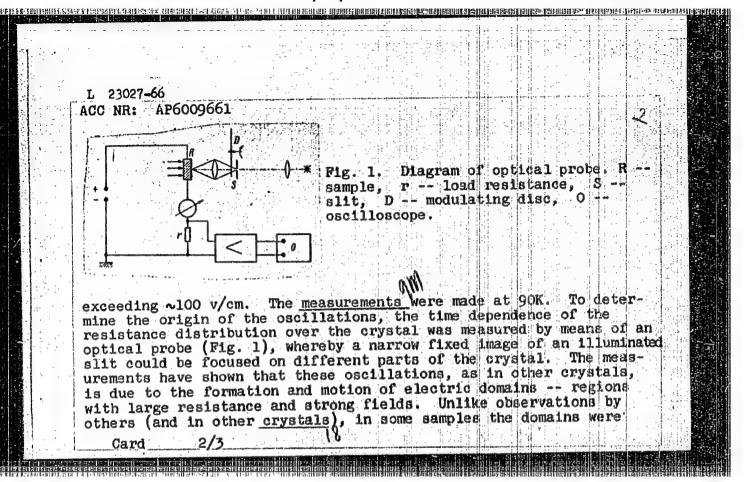


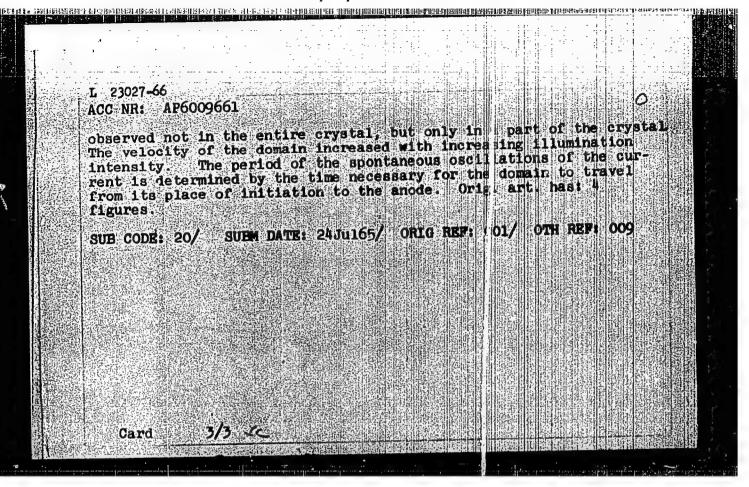


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	AUTHOR: Kagan, H. S.; Kalashnikov, S. G.; Zhdanova, N. G. 44, 55
	TITLE: Nonlinear electrical effects and recombination of the hot electrons in compensated germanium  SOURCE: Physica status solidi, v. 11, no. 1, 1965, 415-428
	TOPIC TAGS: germanium, semiconductor, hot electron effect, recombin- ation impurity center, capture cross section
	ABSTRACT: Steady-state and transient current-voltage characteristics of Cu-doped n-type Ge samples with a partially compensated upper (Ec - 0.26 ev) Cu level were investigated in a field which was varied from 1 to 10 v/cm. In a field greater than 100 v/cm the current-from 1 to 10 v/cm. In a field greater than 100 v/cm the current-voltage curves were found to be sublinear. A study was made of the voltage curves were found to be sublinear. A study was made of the effect of temperature and of the spectrum of the incident light on effect of temperature and coherent low-frequency oscillations were

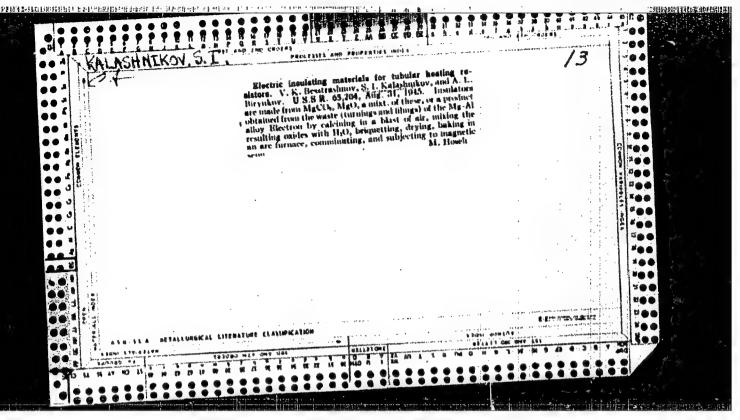
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	AUTHORS: Zhdanova, N. G.; Kagan, M. S.; Kalashnikov, S. G.
	ORG: Institute of Radio Engineering and Electronics, AN SSSR, Moscow (Institut radiotekhniki i elektroniki AN SSSR)
	TITLE: Instability of current and electric domains in compensated germanium
	SOURCE: Fizika tverdogo tela, v. 8, no. 3, 1966, 788-791
	TOPIC TAGS: germanium, photoeffect, crystal structure, semiconductor impurity, eletric excent
	ABSTRACT: This is a continuation of earlier work (Phys. Stat. Sol. v. 11, 415, 1965) where it was found that under certain conditions copper-doped or gold-doped germanium is subject to intense low-
	copper-doped or gold-doped germanium is subject to indeals with the frequency current oscillations. The present article deals with the frequency current oscillations in n-type germanium con-
	properties and nature of these oscillations in n-type germanium con-
	properties and nature of these oscillations in a level, under defi- taining copper with a partially compensated upper level, under defi- taining copper with a partially compensated upper level, under defi-
	taining copper with a partially compensated upper atures, and in fields nite illumination conditions, at nitrogen temperatures, and in fields
	Card 1/3





ACC NR: AP6024347  AUTHOR: Kalashnikov, S. G.; Bonoh-Bruevich, V. L.  ORG: Institute of Radio Engineering and Electronics, Academy of Sciences of the USSR; Moscow  TITLE: On the velocity of space charge waves (electrical domains) in semiconductors  SOURCE: Physica status solidi, v. 16, no. 1, 1966, 197-203  TOPIC TAGS: semiconductor theory, space charge  ABSTRACT: The nonlinear problem of the velocity of space charge waves (electrical domains) which occur when the volume differential resistance becomes negative is studied. Particular attention is paid to the recombination (concentration-controlled) type of instability. A simple explicit formula is obtained for the velocity of stationary space charge waves. The domain velocity is derived for cases in which the Maxwellian relaxation time is much longer or much shorter than the recombination time. In order of magnitude, the results obtained are in agreement with experimental data on domains in Au- and Cu-doped Ge. Unithors thank M. S. Kagan for informing them of his experimental results concerning the domains in Cu-doped Ge and for discussing the namus script. They also thank Yu. F. Sokolov for discussing the manuscript. Crig. art. has in figure and 22 formulas.  SUB CODE: 20/ SUBM DATE: 18Apr66/ ORIG REF: 009/ OTH REF: 014		
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Vibration apparatus for mechanical loading and unloading of paint grinder mills. Knim. prom. no.6:376-377 S '57.

(MIRA 11:1)

1. Khimicheskiy saved imeni Oktyabr'skny revolyutsii, Rostov na-Domn.

(Paint industry--Equipment and supplies)

(Loading and unloading)

KALAShNIKOV

AUTHORS

Kalashnikov S.I., Kichin N.P.,

32-7-13/49

TITLE

Perfecting of the method of Color Defectoscopy (Usovershenstvovaniye metoda tsvetnoy defektoskopii-Kussian) Zavodskaya Laboratoriya, 195/, Vol 23, Nr 7, pp 806-8c8 (W.S.S.A.)

PERTODICAL

ABSTRACT

The mixture of petroleum transformer oil and turpentine is suited only for the treatment of materials of coarse-grained structure as red point. For the determination of extremely small tracks as well as of the intercrystalline corrosion of materials with fine-grained structure it was necessary to find a suitable mixture. Suchs paints were examined as to their ability of resisting light, their adhesive and other properties. It was found that such paints must contain large quantities of benzene and oil.A mixture based upon collodium was found to be favorable. As admixtures to zinc oxide, zinc white and benzene are recommended. The following color compositons are recommended in this paper for defectoscopy: Sudan red 4: 2:95 mibenzene, 5 ml / MK 8/-oil, 1 g red paint. White: 7:70 ml collodium in a sprit-ether solution (for instance colloid oxiline.). (64 units colloxiline, 76 units sulphuric ether, 20 units of rectified spirits). In addition: to ml diluter "RDV" or acetone, 20 ml benzene, 5 g zim white MO per 100 ml of the mixture. The suggested method proved to be successful.

There are 2 figures. Library of Congress.

AVAILABLE Card 1/1

LEYKAND, Mikhail Solomonovich; KALASHNIKOV, S.I., red.; HORUNOV, M.I., tekhn.red.

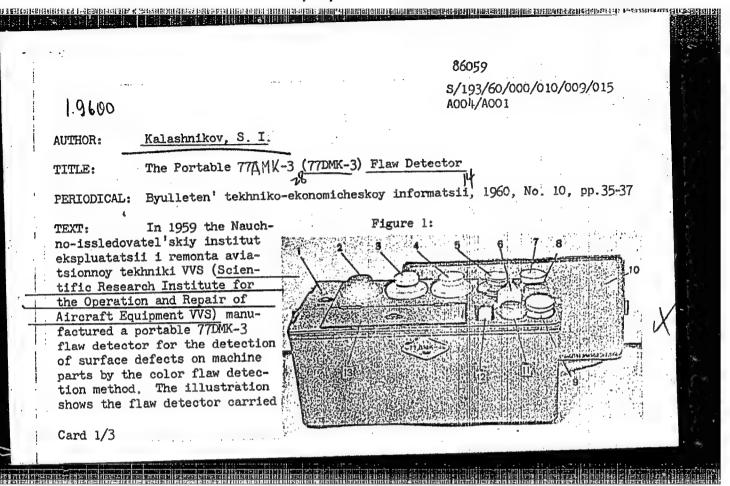
[Design of induction vacuum furnaces and their parts and attachments] Konstruktsii induktsionnykh vakuumykh elektropechei i ikh uslov. Moskra, Goa.energ.isd-vo, 1960. 95 p.; (Biblioteka elektrotermists, no.4).

(Electric furnaces)

"APPROVED FOR RELEASE: 03/20/2001

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86059 S/193/60/000/010/009/015 A004/A001

The Portable 77AMK-3 (77DMK-3) Flaw Detector

out in the shape of a suitcase.

Figure 1:

1 compartment for the paint sprayer; 2 - can with red paint reserve; 3 - can with stock of PAB(RDV) diluent; 4 - can with white paint stock; 5 - can with oil-kerosene mixture; 6 - case with brushes; 7 - can with RDV diluent ready-foruse; 8 - can with ready-for-use red paint; 9 - can with ready-for-use white paint; 10 - lid of flaw detector; 11 - case with brushes for red paint; 12 - calibrating device with grinding cracks; 13 - compartment for keeping the magnifying glass, rags, gloves and instruction manual.

To expose defects, red paint with a great penetrability is applied to the preliminary cleaned surface of the component. Under the effect of capillary forces the paint penetrates into narrow cracks. Then the paint is removed from the surface by a rag slightly wetted with the transformer oil and kerosene mixture. This mixture, removing the red paint only from the surface, protects the paint pentrated into the defect (crack). Then the white paint, which is capable of adsorbing and pull out the red paint from the crack, is applied to the surface. After some time, a red pattern shows on the white ground, indicating the shape and location of the defects. The white and red paints can be used at temperatures form +5 to -40°C. The overall dimensions of the flaw detector are (length x width x height);

Card 2/3

86059

The Portable 77AMK-3 (77DMK-3) Flaw Detector

S/193/60/000/010/009/015 A004/A001

 $380 \times 170 \times 180 \text{ mm}$ ; its weight, completely equipped, amounts to 6 kg. At temperatures of the component in the range of +15 to +25 the paints make it possible to detect cracks on steel parts having a depth of at least 0.01 mm and a width (on the surface) of not less than 0.004-0.006mm. There is 1 figure.

Card 3/3

SVENCHANSKIY, Aleksandr Danilovich; KALASENIKOV, S.I., red.; SHIROKOVA, M.M., tekhn. red.

[Efficient use of electric resistance furnaces] Puti ratsional noi ekspluatateii elektricheskikh pechei soprotivleniia. Moskva, Gosenerg.izd-vo, 1961. 78 p. (Biblioteka elektrotermista, no.6) (MIRA 14:12)

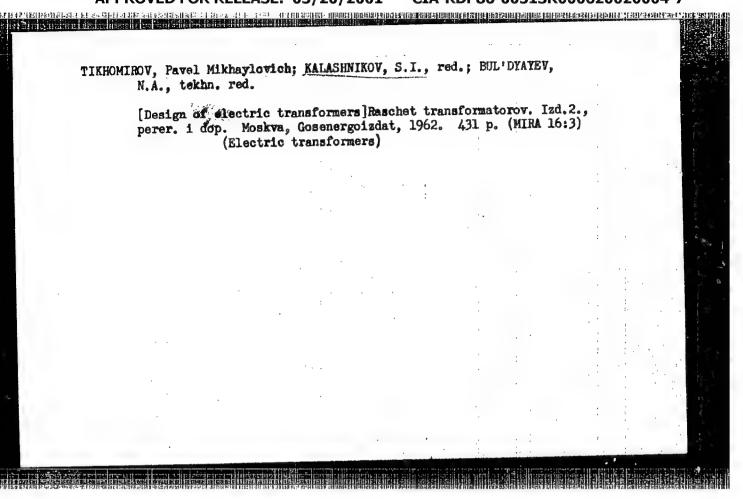
(Electric furnaces)

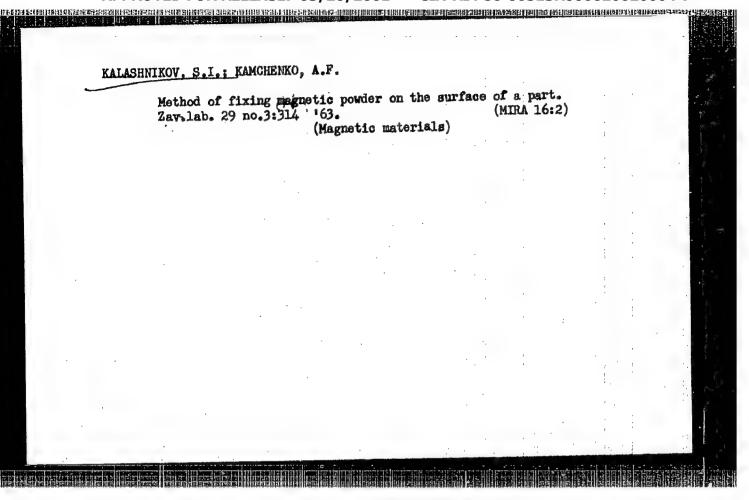
BADMAS, Aleksandr Markovich; KULINICH, Valentin Aleksandrovich; SHA-PIRO, Semen Vol'fovich; KALASHNIKOV, S.I., red.; LARIONOV, G.Ye., tekhn. red.

[Electromagnetic static frequency and phase number converter] Statisticheskie elektromagnitnye preobrazovateli chastoty i chisla faz.

Moskva, Gos.energ.izd-vo, 1961. 207 p. (MIRA 14:12)

(Frequency changers) (Phase converters)





CIA-RDP86-00513R000620020004-7 MAKSIMOV, Aleksandr Aleksandrovich; KALASHNIKOV, S.I., red.; FRIDKIN, L.M., tekhn. red. [Economy of thermal energy in industrial enterprises] Ekonomia teplovoi energii na promyshlennykh predpriiatiiakh. Moskva, Gosenergoizdat, 1963. 117 p.

(MIRA 17:1)

> CIA-RDP86-00513R000620020004-7" APPROVED FOR RELEASE: 03/20/2001

KALASHNIKOV, S.I.; MOROZOV, A.I.; KIRILLOV, V.P.

Electric oscillations due to current saturation in cadmium sulfide. Fiz. tver. tela 6 no.10;3161-3164 0 '64.

(NIRA 17:12)

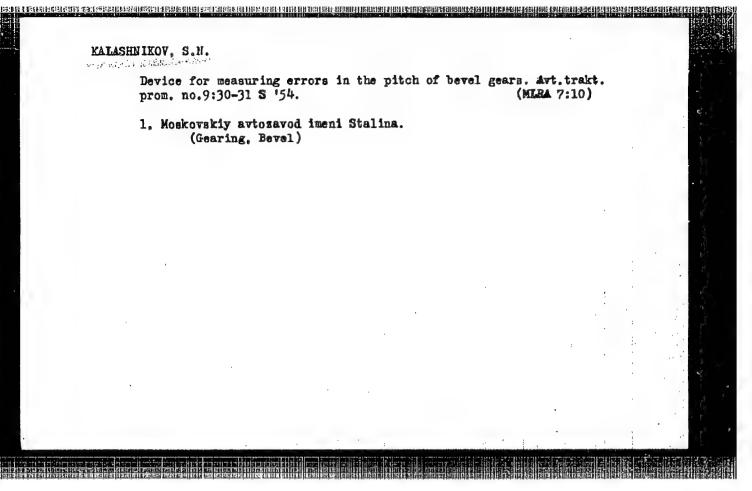
1. Institut radiotekhniki i elektroniki AN SSSR, Moskva.

### KALASHNIKOV, S.N.

Existing machine tools do not permit an accelerated cutting of helical bevel gears. Avt.trakt.prom. no.8:23-26 Ag '53. (MIRA 6:8)

1. Moskovskiy avtozavod im. Stalina.

(Gear-cutting machines)



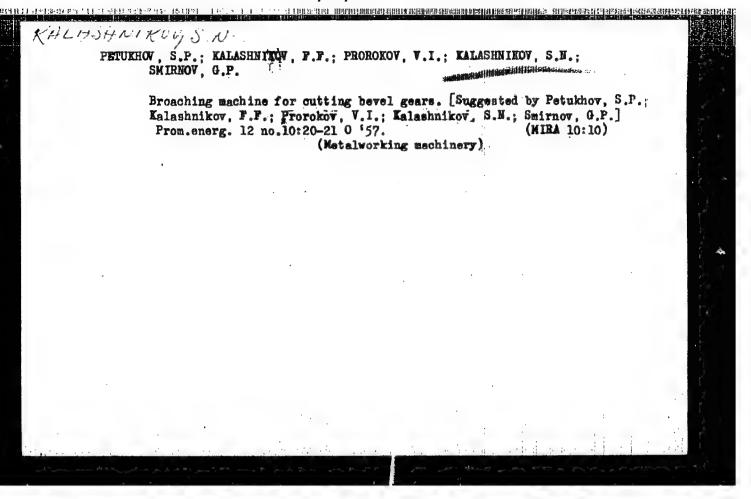
KALASHNIKOV, S. N.: "Investigation of technological factors in the cutting of conic wheels with curvilinear teeth". Moscow, 1955. Min Higher Education USSR. Moscow Automotive Mechanics Inst. (Dissertations for the Degree of Candidate of Technical Sciences)

S0: Knizhnava letopis', No. 52, 24 December, 1955. Moscow.

RAIASHNIKOV, S.N., kandidat tekhnicheskikh nauk.

Rough tooth milling of spiral-conical drive wheels in the direction of delivery. Avt.i trakt.prom. no.4:35-39 Ap '56. (MLRA 9:8)

1. Moskovskiy avtozavod imeni Stalina. (Milling machinery)



AUTHOR:

Kalashnikov, S.N., Candidate of Technical Sciences 113-58-6-14/16

TITLE:

Adaptation of a 12-Inch Head Instead of a 9-Inch Head for the Rough Cutting of Helical Bevel Gears (Primenentye 12-dyuymovoy golovki vmesto 9-dyuymovoy pri chernovom narezanii spiral'no-konicheskikh koles)

PERIODICAL:

Avtomobil'naya promyshlennost', 1958, Nr 6, pp 39-42 (USSR)

ABSTRACT:

As a result of experimental work carried out by the Moscow Automobile Plant imeni Likhachev, more rational models of cutter heads were adapted for production. The aim was to increase the effectiveness of the cog-cutting process of spiral bevel gears. The methods of duplicating and spinning were tested, as well as rough and finish cuttings. In rough cutting by the duplication method, three cutter heads were better than the bilateral, and in the spinning method - cutter heads of clockwise rotation - better than those of counter clockwise rotation and the resistance of the instrument was increased by 70 %. In the finish cutting by bilateral cutting of heads by each method, the higher exactness of the process, the least expenditure of power and mick-cutting of the steel is obtained by the cutter heads in which only one cutter takes part in the process and not two and then one successively. For finish cut-

Card 1/2

113-58-6-14/16

Adaptation of a 12-Inch Head Instead of a 9-Inch Head for the Rough Cutting of Helical Bevel Gears

> ting, one sided cutter heads of clockwise rotation must be used. Their resistance is almost twice as high as that of counter clockwise rotating heads. The analytical and graphic comparison of various cutter heads used in the 1160-ZIL bench showed that the productivity of the 1160-ZIL bench increased by 35% and the head resistance increased 2.5 times when the 12-inch cutter head of clockwise rotation replaced the 9-inch head of counter clockwise rotation. The resistance of finishing cutter heads and the exactness of the cutting of cogs is identical with both 12 and 9-inch cutter heads. There are 4 graphs, 1 table and 1 figure.

ASSOCIATION: Moskovskiy avtozavod imeni Likhacheva (The Moscow Automobile Plant imeni Likhachev)

Card 2/2

1. Gears--Production--Processes 2. Cutting tools--Effectiveness

#### PHASE I BOOK EXPLOITATION

SOV/4633

### Kalashnikov, Sergey Nikiforovich, Candidate of Technical Sciences

- Opyt primeneniya ratsional'nykh konstruktsiy reztsovykh golovok (Experience in the Use of Efficient Designs of [Gear] Cutters) Moscow, Mashgiz, 1960. 121 p. 5,000 copies printed.
- Ed. of Publishing House: I. I. Lesnichenko; Tech. Eds.: A. F. Uvarova and G. V. Smirnova; Managing Ed. for Literature on Metalworking and Machine-Tool Construction: V. I. Mitin, Engineer.
- PURPOSE: This book is intended for designers, technicians, and foremen in gear cutting.
- COVERAGE: Problems connected with the selection of basic parameters for blades and face-milling cutters for curved-tooth bevel gears are discussed. The author presents results of investigations and experience gained in the use of various cutters for roughing and finishing gears by the generating and copying methods. Designs of cutters described in the book have been introduced into production at the Avtozavod imeni Likhacheva (Automobile Flant im. Likhachev).

Card 1/6

YAKIMANSKIY, V.V., kand.tekhn.nauk; SHLYAPIN, N.A.; KIRICHINSKIY I.I.; SHKLYAROV, I.N.; KALASHNIKOV, S.N., kand.tekhn.nauk

Using new techniques of hot rolling of teeth in making spiral bevel gears. Avt.prom. no.9:39-43 S 160. (MIRA 13:9)

1. Nauchno-issledovatel'skiy institut tekhnologii avtomobil'noy promyshlennosti i Moskovskiy avtozavod imeni Likhacheva.

(Gear shaping machines)

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KALASHNIKOV, S.N., kand. tekhn. nauk; NOVIKOV, N.S.

Increasing the efficiency of machining splined shafts. Avt. prom. 29 no.7:37-40 Jl 163. (MIRA 16:8)

1. Moskovskiy avtozavod imeni Likhacheva. (Milling machines)

KALASHNIKOV, S.N.; KOGAN, G.I.; KOZLOVSKIY, I.S.; KORZINKIN, V.I.;

MARKOV, N.N.; SYROYEGIN, A.A.; TAYTS, B.A., prof., doktor
tekhn. nauk, red.; TROFIMOVA, Ye.I., kand. tekhn. nauk,
retsenzent; IVANOVA, N.A., red.izd-va; EL'KIND. V.D.,
tekhn. red.

[Manufacture of gear wheels] Projected to Theirtele below

[Manufacture of gear wheels] Proizvodstvo zubchatykh koles; spravochnik. [By] S.N.Kalashnikov i dr. Moskva, Mashgiz, 1963. 683 p. (MIRA 16:12)

KALASHNIKOV, S.N., kand.tekhn.nauk; GLUKHOV, I.I.

Efficient cutter head for finish machining of bevel gear teeth.

Avt.prom. 30 no.1:32-35 Ja '64. (MIRA 17:3)

1. Moskovskiy avtozavod imeni Likhacheva.

KALASHNIKOV, S.N., kand.tekhn.nauk; ORLOV, I.V., inzh.

Manufacturing high-precision cylindrical gear wheels under mass production conditions. Vest.mashihostr. 44 no.7:43-49 Jl '64.

(MIRA 17:9)

<del>and some season of the season</del> KALASHNIKOV, S.N., kand. tekhn. nauk; GLUKHOV, I.1. Increasing the efficiency of rough cutting of spiral-bevel pinion gears. Avt. prom. 31 no.2:33-36 F '65. 1. Moskovskiy avtozavod imeni Likhacheva. (MIRA 18:3)

CIA-RDP86-00513R000620020004-7" APPROVED FOR RELEASE: 03/20/2001

KALASHNIKOV, S.N., kand.tekhn.nauk; TROFILEYEV, N.N.

Advanced technology for machiring gear-wheel teeth of the distributing shaft of the ZII-130 engine. Avt.prom. 31 no.10:33-36 0 '65. (MIRA 18:10)

1. Moskovskiy avtozavod imeni Likhacheva.

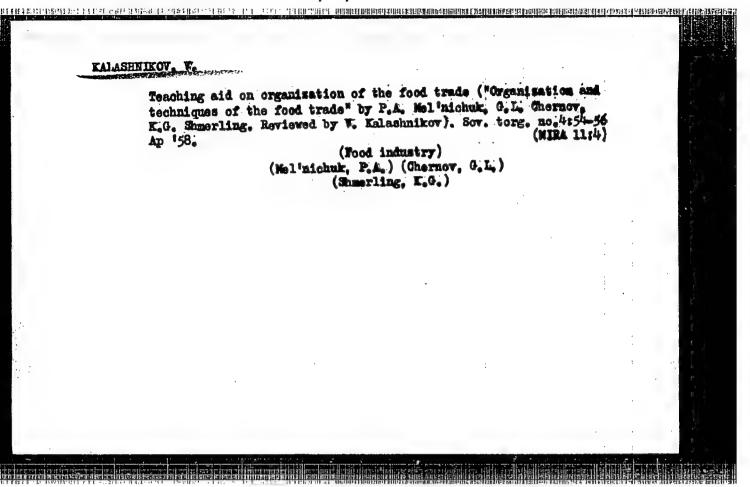
KALASHNIKOV, T.N.

School dairy.Politek.ebuch. no.9:82 S '59.

(MIRA 12:12)

1. Neshovskaya srednyaya shkola Yelovskogo rayona Portuskoy oblasti.

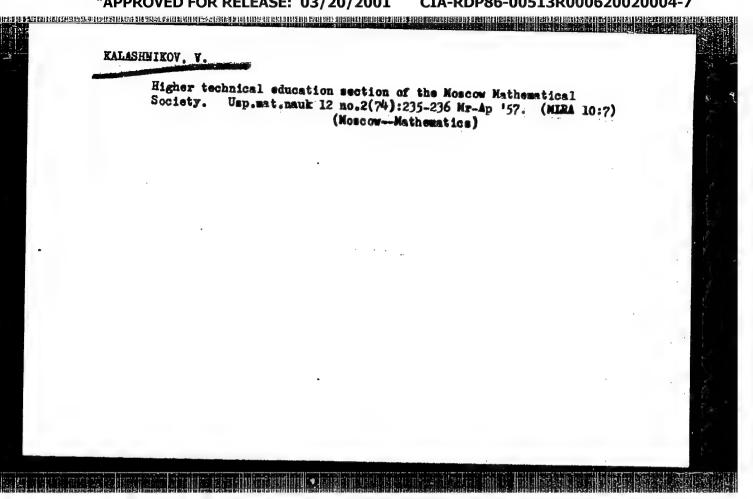
(Dairying-Study and teaching)



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		,		ridely-usic type of the est), t	o" No 4,	Membe	
			the cryst	-used pickups are pe complete with le 'Muzradiosoyuz' the PZ-1 and AFR	pp 58-59	of Phonogram, Ufa Do	
			the electromagnetic crystal APR separate and sound reproand a competition for conducted.	ed pickups are the "Zvezde" electro- complete with arm (produced by the RAAZ Muzradiosoyuz' and the Sverdlovsk hay- Muzradiosoyuz' and the pickups with		Phonographs Pickups Phonograph Pickups, Ufa Dossaf Radio Cl	
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	Triumph of the elev. prom. 23	Party in reclaiming virgin no.11:4-6 N 157.	sud waste ta	(MIRA 11:1)	
	1. Zamestitel	ministra khleboproduktov I (Reclamation of land)	RSFSR. (Grein)		
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Vypolnili slovo, dannoye Vozhdyu. (O dosrochnom vypolnenii gos. plana khlebozagotowok. ukr. SSR). Zagotowki s.-kh. produktov, 1949, No 2, s. 15-19



CIA-RDP86-00513R000620020004-7" APPROVED FOR RELEASE: 03/20/2001

AUTHOR:

Kalashnikov

507/84-58-8-43/59

TITLE:

About the General Layout of Helicopters (O vneshney komponovke

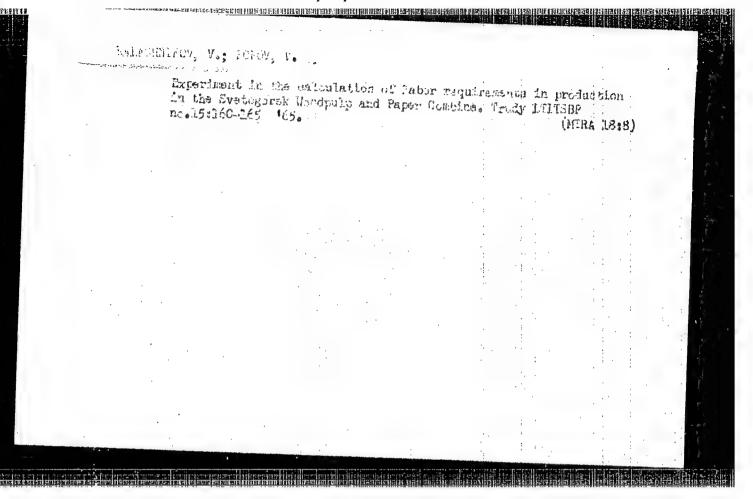
vertoletov)

PERIODICAL: Grazhdanskaya aviatsiya, 1958, Nr 8, p 51 (USSR)

ABSTRACT:

According to the editor's note, this letter is one of many dealing with certain deficiencies in the trim and controllability of Mi-1 and Mi-4 helicopters. This author is concerned with such problems as the changeover of plug-ins for airfield electric power, compressed air, and fuel and oil to the left side of the fuselage thus making it easier for the pilot to watch operations. It is recommended that cargo and work compartments be placed nearer the rotor axis for better stability during loading and unloading while hovering; at present, every movement of cargo or men destroys the balance of the helicopter. For the same reason the direction of the rotation of the rotor should be reversed, i.e., made to rotate counterclockwise when looked at from above. The stabilizing propeller should be rotated clockwise if looked at from the left side to compensate for list caused by the rotor.

Card 1/1



#### "APPROVED FOR RELEASE: 03/20/2001

CIA-RDP86-00513R000620020004-7 

L 44381-66 EWT(m)/T

ACC NR AP6022405 (A)

SOURCE CODE: UR/0317/66/000/002/0046/0049

AUTHOR: Goryacheva, V.; Kalashnikov, V.; Shekhter, Yu.

ORG: none

TITLE: New lubricants and additives

SOURCE: Tekhnika i vooruzheniye, no. 2, 1966, 46-49

TOPIC TAGS: liquid metal lubricant, lubricant additive

ABSTRACT: Soviet industry has recently developed and is producing serially the following inhibiting liquid lubricants (1) NG-203(A, B, C-which differ in viscosity and inhibitor content). The inhibitor is a concentrate of calcium sulfonate. Brands B and C which are the more liquid serve to lubricate the internal parts of machines, machine tools and instruments. Brand A is recommended for the external surfaces; 2) NG-204 and NG-204u are used for equipment exposed to precipitation. NG-204 is recommended for surfaces of complex shape, NG-204u for external surfaces (casings

1/2

L 44381-66 ACC NR: AP6022405	
housings); 3) K-15, K-17 and K-19. The components, st viscosity, and other characteristics of all the lubricants "Neftegar." Plant in Moscow has developed the anticorros "AKOR-1" which improves the protective properties of m 2 tables.	are given in two tobles The
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hs Card 2/2	

KALASHNIKOV, V. A. and VIN'KOV, M. P.

"Experience in Operating the EV-80-3 Electronic Computer" a paper presented at the Conference on Methods of Development of Soviet Mathematical Machine-Building and Instrument-Building, 12-17 March 1956.

Translation No. 596, 8 Oct 56

SOV/119-58-8-2/16 Kalashnikov, V. A., Krassov, I. M., AUTHORS:

Petrov. V. V.

On the Evaluation of Servomechanisms (Ob otsenke TITLE:

i sravnenii servomeknanizmov)

Priborostroyeniye, 1958, Nr 8, pp. 7 - 10 (USSR) PERIODICAL:

A servomechanism is a device for magnifying power output, which makes use of a foreign source for the purpose of increasing ABSTRACT: energy (Refs 1 and 2). A weak control signal is to be modeled

at its output, which had been fed in at its input with errors

being kept as small as possible.

On the basis of an electrohydraulic control mechanism it is shown to what extent its dynamic and static characteristics correspond to constructional directives given, and in what way the mechanism fulfills its task within the framework of the

entire process of control.

Particular care must be taken in order that a servo-mechanism with such an amplitude-phase characteristic be selected in the case of which the dynamics of the mechanism exercises hardly any influence upon the constancy of work and the process of

Card 1/3

SOV/119-58-8-2/16

On the Evaluation of Servomechanisms

control.

The operation of a servo-mechanism is characterized by the following indices:

- 1) Energetic indices as e.g.:
- a) control output, b) the work of control, c) the maximum effective power output, d) nominal stress, e) maximum stress.
- 2) Static indices as e.g.:
- a) the course taken by the static characteristic, b) the nominal velocity of displacement, c) the nominal amount of the control signal, d) the zone of insensibility.
- 3) Dynamic indices.

These indices characterize processes of transmission in servomechanism when a single shock-like action brings about a change from without, or if a sinusoidal modification of the external action influences the phenomenon of motion in the servomechanism.

Such indices are: a) the time of supply, b) the time needed for re-establishing the normal velocity of displacement, c) time of slowing down, d) reaction time of the servo-mechanism, e) the time constant of the servo-mechanism.

Card 2/3

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On the Evaluation of Servomechanisms

SOV/119-58-8-2/16

There are 6 figures and 7 references, which are Soviet.

1. Servomechanisms—Effectiveness 2. Servomechanisms—Control systems 3. Control systems -- Performance

Card 3/3

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	Moscow. Vysahays telchniches matematicheskich mashin	Wychislitel'nays tekhniks (G 153 p. (Series: Moscow, Sbornik, No. 2) 2,500 cop	Md.: D.V. Anishov, Candida D.T. Model: and A.F. Uva Machine Building and Inst	FURNAR: This book may be uspecialising in computer engineering and technical		2003	Systems With Discrete Element	the registration and the second and	Anistacy, B.V., Candidate of Candidate of Technical Scient Device for Transforming the Pre- graphics at Candida of Tech Engines. Cartain Frincible	Viacento, V.I., Cardidate of Froresor, Jan. Desort, Try. Matter of Moreting the Lange	Shrender, This. Candidate of the Connection Determen the P	Rechister, B.V., Candidate of Candidate of Technical Scien Device for the Control of Me	Vasiliyev, O.P., Engineer, an Econosical Selection of C	Anisimov, B.V., Candidate of Vinogradov, Engineer. On th presentation of Continuovely	Apreyder, No. A., Candidate Solution of Boundary Value P Approximations	Markov, G.Ya., Engineer. Ca Control of Electronic Comput	M.S. Saplin, Engineer. Front Frinced France. Signs Falashevskiy, A.M., Engines: Components of Computers	Charverikov, V.H., Candidate Integrating Drive With Elect	Kalashnikov, V.A., Engineer.	Minstack.M.M.», Candidate o Machanisma for Programmed Co	7 St. 11 St. 10 -1

KAIRSHNIKOU, V.A.

28(1)

PHASE I BOOK EXPLOITATION

S0V/2087

Elementy sistem avtomaticheskogo regulirovaniya. ch. 1:
Chuvstvitel'nyye usilitel'nyye i ispolnitel'nyye elementy
(Elements of Automatic Control Systems. pt. 1: Sensing,
Amplifying and Control Elements) Moscow, Mashgiz, 1959. 722 p.
(Series: Osnovy avtomaticheskogo regulirovaniya, t 2) Errata
slip inserted. 13,000 copies printed.

Reviewers: F. F. Galteyev, Candidate of Technical Sciences,
V. A. Karesev, Doctor of Technical Sciences, P. P. Klobukov,
Candidate of Technical Sciences, V. V. Petrov, Candidate of
Technical Sciences, Yu. D. Ragozin, Candidate of Technical Sciences,
Yu. R. Reyngol'd, Engineer, B. A. Ryabov, Doctor of Technical
Sciences, B.D. Sadovskiy, Candidate of Technical Sciences,
A. G. Saybel', Candidate of Technical Sciences, and A. A. Shevyakov,
Candidate of Technical Sciences; Scientific Eds.: I. M. Vitenberg,
Candidate of Technical Sciences, A. I. Moldaver, Candidate of
Technical Sciences, and Yu. Ye. Ruzskiy, Candidate of Technical
Sciences; Ed. of Series: V. V. Solodovnikov, Doctor of Technical
Sciences, Professor; Eds. of Publishing House: G. F. Polyakov,
A. G. Akimova, and G. M. Konovalov; Tech. Eds.: A. Ya. Tikhanov

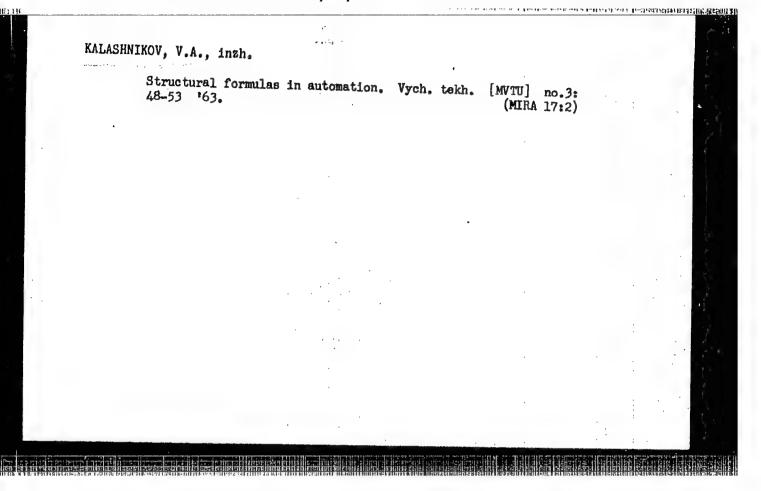
Card 1/13

Elements of Automatic Control Systems (Cont.)

SOV/2087

Sciences, paragraph 1 of Chapter VIII; K. Ye. Dmitriyev, Candidate of Technical Sciences, paragraph 2 of Chapter XIII; Y. A. Kalashnikov, Engineer, Chapter XIV; P. P. Klobukov, Candidate of Technical Sciences, paragraphs 2 and 3 of Chapter VIII; P. F. Klubnikin, Candidate of Technical Sciences, Chapter XIII; I. M. Krassov, Candidate of Technical Sciences, paragraph 1 of Chapter XIII, and Chapter XIV; D. S. Pel'por, Doctor of Technical Sciences, paragraphs 1-3of Chapter III; V. V. Petrov, Candidate of Technical Sciences, paragraph 1 of Chapter XIII, and Chapter XIV; M. A. Rozenblat, Doctor of Technical Sciences, Chapter VII; Yu. Ye. Ruzskiy, Candidate of Technical Sciences, paragraphs 1, 3-5 and 8-10 of Chapter 1, paragraphs 2-5, 12, 13 and 17 of Chapter II, paragraph 3 of Chapter XIII, and Chapter IX; B. D. Sadovskiy, Candidate of Technical Sciences, Chapter X; A. A. Sokolov, Candidate of Technical Sciences, Chapter X; A. A. Sokolov, Candidate of Technical Sciences, Chapter XI; G. M. Ulanov, Candidate of Technical Sciences, paragraphs 9-13 of Chapter IV, paragraph 4 of Chapter X, and Chapter XI; G. M. Ulanov, Candidate of Technical Sciences, paragraph 1 of Chapter II; Ye. V. Filipchuk, Candidate of Technical Sciences, paragraph 1 of Chapter II; Ye. V. Filipchuk, Candidate of Technical Sciences, paragraphs 6-11, 14-16 and 18-29 of Chapter II;

Card 3/13



KALASHNIKOV, Viktor Anatolizevich; SABIROV, Rais Shakirovich; RUDAKOVA, L.A., red.

["Ufa" welding torch; practical manual for introducing the use of propane-butane mixturer in the flams machining of metals] Svarochnaia gorelka "Ufa"; prakticheskoe posobie po vnedreniiu v gamoplamennuiu obrabotku metallov propan-butovykh smesei. Ufa, Bashkirskoe knizhnoe izd-vo, 1963. 102 p. (MIRA 18:10)

YEVSTRATOVA, N. I.; KALASHNIKOV, V. B.; LAPIN, V. N.; SHEKHTER, Yu. N.

Ottlining thiosalts from the tar of Kasphpir shales. Trudy
VHIIT no. 11:144-154 '62. (MIRK 17:5)

KAIASHNIKOV, V.D., inzhener; TITOV, A.A., inzhener.

The new Ulan Bator-Sining railroad line. Zhel.dor.transp. 37 no.1; 71-72 Ja '56. (MLRA 9:3)

(Asia--Railroads)

TIKHOMINOV, V.V.; KALASHNIKOV, V.D.

Insulating reinforced-concrete reservoirs (from "Konsorv és papirknipar, "July-Aug. 1956). Kens. i. ov. pros. 14 no.1:43-24 Ja '59.

(Hungary-Canning industry-Equipment and supplies)

(Insulating materials)

KALASHNIKOVA, L.M., kand. ekon. nauk, dots.; KALASHNIKOV. V.D.;
YEPIKHIN, P.S.; LAPSHINA, Ye.A.; PENTKOVSKIY, N.I., prof.,
retsenzent; GORBUSHIN, P.B., retsenzent; RYABOVA, O.A., red.

[Economics of the building materials industry] Ekonomika promyshlennosti stroitel'nykh materialov. [By] L.N.Kalashnikova i dr. Moskva Vysshaia shkola, 1964. 307 p. (MIRA 17:10)

1. Zaveduyushchiy kafedroy ekonomiki i organizatsii Moskovskogo inzhenerno-stroitel'nogo instituta (for Pentkovskiy). 2. Chlen-korrespondent Akademii stroitel'stva i arkhitektury SSSR (for Gorbushin).

KALASHNIKOVA, L.M., kard. ekon. nauk; YEFIKHIN, P.S.; ZAGORCHIK, M.M.
[deceased]; KALASHNIKOV, V.D.; NAGIEIN, G.V.; RYABOVA,O.A.,
red.

[Organization and planning of production in building materials industry enterprises] Organizatsiia i planirovanie
proizvodstva na predpriiatiiakh prosyshlennosti strottelinykh materialov. IAroslavl', Hosvuzizdat, 1963. 346 p.

(MIRA 18:3)

KALASHNIKOV, Viktor Dmitriyevich; KALASHNIKOVA, Lyudmila Mikhaylovna; RYABOVA, O.A., red.

[Establishing technical standards for work processes in building materials industry enterprises] Tekhnicheskoe normirovanie protsessov truda na predpriiatiiakh promyshlennosti stroitel nykh materialov. Moskva, Vysshaia chkola, 1965.

242 p. (MIRA 18:8)

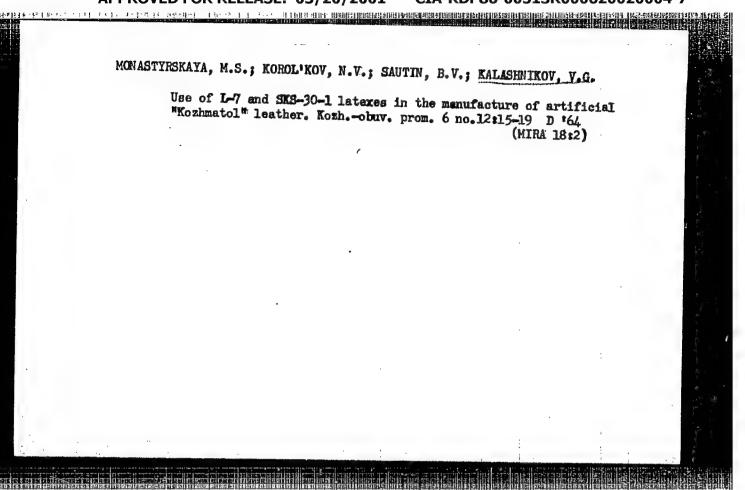
KALASINIKOV, V. F.; VORONTSOV-VEL'YAMINOV, B. A.

"Definitive curve describing the variation in brightness of nova lacertae 1910," Astron.

Zhur., 16, No 5, 1939.

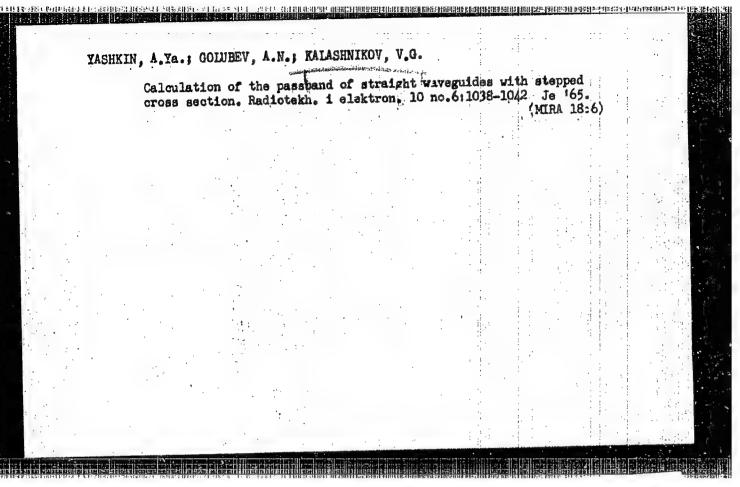
Report U-1518, 23 Oct 1951

SOURCE CODE: UR/0111,/66/000/010/0036/0038 ACC NR: AP6034137 (A) AUTHOR: Kalashnikov, V. F. (Candidate of technical sciences) ORG: none TITLE: On statistically estimating the reliability of a turbogenerator set SOURCE: Energomashinostroyeniye, no. 10, 1966, 36-38 TOPIC TAGS: turbine, electric power plant, statistics, statistic distribution, turbogenerator, mechanical failure, probability, reliability/ PVK-200-1 turbogenerator ABSTRACT: In this paper problems of statistically estimating the reliability of a turbogenerator set, failures, and recoveries are examined. The PVK-200-1 turbogenerator set is used as an example. An unordered set of N=66 random realizations of the operating time between failures of a PVK-200-1 and an unordered set of N = 61 random realizations of recovery time were studied. These data were obtained from analysis of the operation of these units at electric power stations. It was found that a turbogenerator set is a complex recoverable system. The flow of failures obeys an exponentional law. The flow of recoveries after failures of various elements also obeys an exponential law. A final determination of the distribution law of failures and recoveries in specific cases can be made by analysis of statistical data. Orig. art. has: 4 formulas. ORIO REF: SUBM DATE: none/ SUB CODE: 10/ 62-135.00h.15



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AUTHOR:	Kalashnikov, V	. G.; Golod, O.	U	21.317.7	73	
TITLE: /	method for con No. 173273	tinuously vary	ing the phase o	f a sinusoidal o	scillation.	
SOURCE:	Byulleten' izob	reteniv i tova	mukh znakov	0. 15, 1965, 43		
TOPIC TAG	S: oscillation	, electronic e	luipment, phase	control, phase	variation,	
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of a francis	3-58-7-13/36
AUTHOR:	Kalashnikov, V.I., Secretary of the Party Office  Not Only to Teach, but Also to Educate (Ne tel'ko uchit!, no
ROTHS	we only to Teach, but Also to Educate
TITLE:	1 VOSPILITON (USSR)
PERIODICAL:	Vestnik vysshey shkoly, 1958, hi it. It.  The author describes the role of the Komsomol organization in the author describes the role of the Lugansk Pedagogical The author of future teachers at the Lugansk Pedagogical The educational work is
ABSTRACT:	Institute imeni T.G. Shevchenko. Industries of the conducted with various industries of the students become acquainted with various industries in the plants. Students become acquainted with various in the plants. In them work on different machines in the plants. Students also work in various laboratories and worksheps of town; some of them work in various laboratories or take part in the institute. In their free time they visit various schools the institute. In the laboratories or take part in and help the teachers in the laboratories or take part in the institute. The Komsomol has organized useful recreation school circles. The Komsomol has organized buildings.
ASSOCIATION	N: Luganskiy pedagogicheskiy institut imeni T.G. Shevchenko) (The Lugansk Pedagogical Institute imeni T.G. Shevchenko)
Card 1/2	

(st. Chernovtsy); SHAMIS, I.M., glavnyy bukhgalter
(st. Chernovtsy); SOLOBATEMEO, L.D., ekonomist (st. Chernovtsy)

Advanced technology of car repair and improved cost accounting.
Zhel. dor. transp. 38 no.8:54-57 Ag '56. (MLRA 9:10)

1. Zamestitel' nachal'nika Chernovitskogo vagonnogo uchastka
(for Kalashnikov).
(Railroads--Cars--Mainteman-Mad repair)

VASIL'YEV, V.G., kand.tekhn.nauk; IOMAKIN, V.P., inzh.; KAIASHMIKOV.

V.I., inzh.

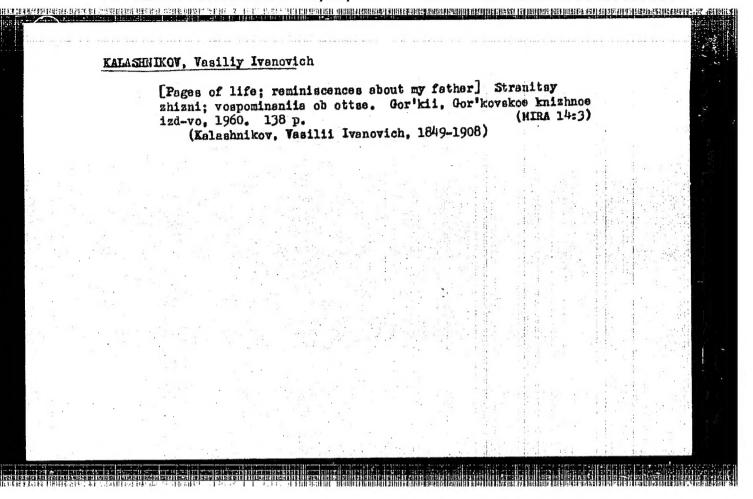
Electrom model of electromechanical lifting and thrust mechanisms on excavating machines with simultaneous operation on the part of these mechanisms. Izv. vys. ucheb. sav.; gor. shur.

no.9:109-116 '60.

1. Khar'kovskiy politekhnicheskiy institut im. V.I. Lonina.

(Excavating machinery—Electromechanical analogies)

(Electronic analog computers)



XALASHNIKOV, V.I.; inzh.; XUZIN, M.D., inzh.; ROZENFEL'D, V.S., inzh.;
SHAYEL'ZON, M.V., insh.

Automatization of technological processes in autoclaves.
Stroi. mat. 5 no.6:18-20 Je '59. (MIRA 12:8)

(Autoclaves) (Automatic control)